

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	125844	(semiconductor or semi-conductor or (semi near conductor))near3 laser	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 11:58
S2	6408	((semiconductor or semi-conductor or (semi near conductor))near3 laser) and ((surface near emit\$4) or surface-emit\$4)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:01
S3	2363	((semiconductor or semi-conductor or (semi near conductor))near3 laser) and ((surface near emit\$4) or surface-emit\$4) and coat\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:01
S4	2307	((semiconductor or semi-conductor or (semi near conductor))near3 laser) and ((surface near emit\$4) or surface-emit\$4) and coat\$4	US-PGPUB; USPAT	AND	ON	2006/01/03 12:08
S5	30895300	(@pd or @rlad or @prad or @ad)<"20000809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:12
S6	1244	S4 and S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:09
S7	40017	("372").CLAS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/03 12:10
S8	519	S6 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:10

S9	27732348	(@pd)<"20000809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:13
S10	570	S9 and S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:18
S11	275	S10 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:30
S12	46883	\$5reflect\$4 near coating	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 12:31
S13	126	S11 and S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 13:51
S14	1355	(372/75).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/01/03 13:52
S15	584	(372/75).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/01/04 09:09
S22	15	\$\$56006492\$\$	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/03 16:54

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S1	74916	(semi near conductor or semi-conductor or semiconductor) and laser and active	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/04 09:12
S2	13128	(semi near conductor or semi-conductor or semiconductor) and laser and active and reflective	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/04 09:16
S3	13444	(semi near conductor or semi-conductor or semiconductor) and laser and active and \$4reflective	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/04 09:19
S4	2819	(semi near conductor or semi-conductor or semiconductor) and laser and active and (\$4reflective near coat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/04 09:20
S5	2847	(semi near conductor or semi-conductor or semiconductor) and laser and active and (\$5reflective near coat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/04 09:32
S6	459	(semi near conductor or semi-conductor or semiconductor) and laser and active and (\$5reflective near coat\$3) and stripe	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 11:06
S7	85	broad near stripe near laser	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 14:02
S9	1172	VCSEL and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 15:03

S10	3630	((surface near3 emitting)) near3 laser) and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 15:17
S11	65	((surface near3 emitting)) near3 laser) and (semi near3 conductor)and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 15:48
S12	2568	((surface near3 emitting)) near3 laser) and ((semi near3 conductor) or semiconductor)and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/05 15:49
S13	1839	((surface near3 emitting)) near3 laser) and (((semi near3 conductor) or semiconductor) near3 laser)and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 08:39
S14	1459	((surface adj3 emitting)) near3 laser) and (((semi near3 conductor) or semiconductor) near3 laser)and (@pd)<"20010809"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 09:30
S15	0	((surface adj3 emitting)) near3 laser) and (((semi near3 conductor) or semiconductor) near3 laser)and (@pd)<"20010809" and "371".clas.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 09:30
S16	615	((surface adj3 emitting)) near3 laser) and (((semi near3 conductor) or semiconductor) near3 laser)and (@pd)<"20010809" and "372".clas.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 10:09
S17	844	S14 not S16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 12:19

S18	35344	cylindrical near3 lens	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 12:19
S19	18951	cylindrical near3 lens and laser	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 14:40
S20	38	cylindrical near3 lens and (broad near3 stripe near3 laser)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 14:51
S21	39	(cylindrical or cylinder) near3 lens and (broad near3 stripe near3 laser)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 16:55
S23	2170	((cylindrical or cylinder) near3 lens) and ((broad near3 stripe near3 laser) or (laser near3 array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/06 17:00
S24	39	((cylindrical or cylinder) near3 lens) and (broad near3 stripe near3 laser)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/09 08:28
S25	39	((cylindrical or cylinder) near3 lens) and (((broad near3 stripe) or broadstripe) near3 laser)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/09 08:27
S26	456	((cylindrical or cylinder) near3 lens) and (broad near5 laser)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/09 08:28

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S1	572	silica near3 glass and "372".clas.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/11 11:27
S2	3	(("6263002") or ("5136598") or ("5220572")).PN.	US-PGPUB; USPAT	OR	OFF	2006/01/11 12:24
S3	1769	ingaasp same substrate same laser same form\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/12 09:19
S4	240	ingaasp same substrate same laser same diode same form\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	AND	ON	2006/01/12 09:19